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Substitute for form 1449/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT Date Submitted: April 13, 2009 (use as many sheets as necessary)		Complete if Known	
		Application Number Filing Date First Named Inventor Art Unit Examiner Name Attorney Docket Number	10/588,698 02/02/2005 Tadahiro OHMI et al. 2895 Caridad Everhart 039262-0156
Sheet	1	of	1

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
	B1	US - 4,484,979	11-27-1984	STOCKER	
	B2	US - 5,296,094	03-22-1994	SHAN et al.	
	B3	US - 6,025,255	02-15-2000	CHEN et al.	
	B4	US - 6,159,862	12-12-2000	YAMADA et al.	

UNPUBLISHED U.S. PATENT APPLICATION DOCUMENTS					
Examiner Initials*	Cite No. ¹	U.S. Patent Application Document	Filing Date of Cited Document MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Documents	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Country Code ³ Number ⁴ Kind Code ⁵ (if known)				
	B5	JP - 08-222551	08-30-1996	SONY CORPORATION		A
	B6	JP - 09-027472	01-18-1997	SONY CORPORATION		A

NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.			T ⁶
	B7	GOTO et al., "A New Microwave-Excited Plasma Etching Equipment for Separating Plasma Excited Region From Etching Process Region," Japanese Journal of Applied Physics, Vol. 42, Part 1, No. 4B, April 2003, pp. 1877-1891.			
	B8	KAIHARA et al., "Damage-Free Contact Etching Using Balanced Electron Drift Magnetron Etcher," Proceedings of ISSM 2000, The 9 th International Symposium on Semiconductor Manufacturing, Vol. Conf. 9, September 26, 2000, pp. 102-105.			
	B9	MATSUI et al., "Mechanism of Highly Selective SiO ₂ Contact Hole Etching," Plasma Sources Science and Technology, Institute of Physics Publishing, Vol. 11, No. 3A, August 1, 2002, pp. A203-A205.			

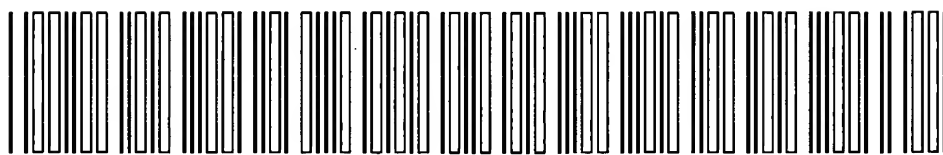
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